RECTRON
SEMICONDUCTOR
TECHNICAL SPECIFICATION

FFM1600W

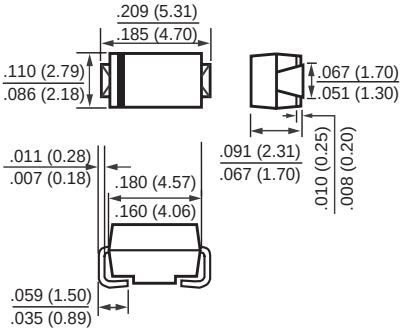
FAST RECOVERY RECTIFIER

VOLTAGE 1600 Volts CURRENT 0.5 Ampere

FEATURES
* Fast switching
* Low leakage
* Low forward voltage drop
* High current capability
* High currenf surge
* High reliability

MECHANICAL DATA
* Case: Molded plastic
* Epoxy: Device has UL flammability classification 94V-O
* Lead: MIL-STD-202E method 208C guaranteed
* Mounting position: Any

SMX



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS
Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

MAXIMUM RATINGS (At T_A = 25°C unless otherwise noted)

RATINGS	SYMBOL	FFM1600W	UNITS
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	1600	Volts
Maximum RMS Voltage	V_{RMS}	1120	Volts
Maximum DC Blocking Voltage	V_{DC}	1600	Volts
Maximum Average Forward Rectified Current at T_A = 25°C	I_O	0.5	Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	25	Amps
Typical Junction Capacitance (Note 2)	C_J	15	pF
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to + 150	°C

ELECTRICAL CHARACTERISTICS (At T_A = 25°C unless otherwise noted)

CHARACTERISTICS	SYMBOL	FFM1600W	UNITS
Maximum Instantaneous Forward Voltage at 0.5A DC	V_F	1.8	Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage T_A = 25°C	I_R	5.0	uAmps
Maximum Full Load Reverse Current Full Cycle Average, .375" (9.5mm) lead length at T_L = 55°C		100	uAmps
Maximum Reverse Recovery Time (Note 1)	trr	300	nSec

NOTES : 1. Reverse Recovery Test Conditions: I_F = 0.5A, I_R = -1.0A, I_{RR} =- 0.25A
2. Measured at 1 MHz and applied reverse voltage of 4.0 volts

RATING AND CHARACTERISTIC CURVES (FFM1600W)

FIG. 1 - TYPICAL FORWARD CURRENT DERATING CURVE

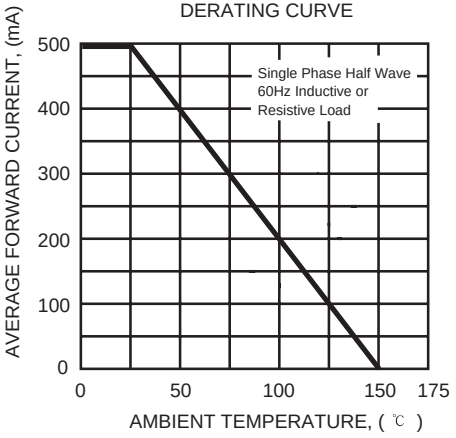


FIG. 2 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

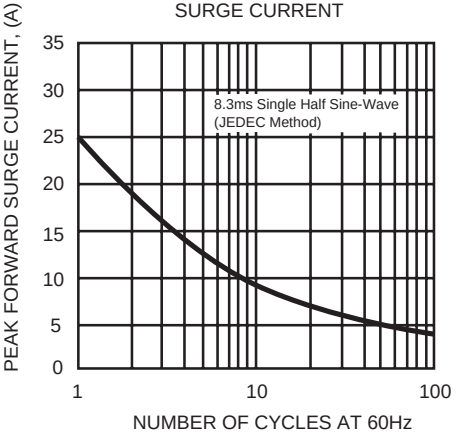
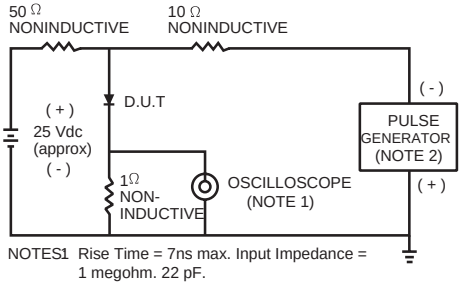


FIG. 3 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm. 22 pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.